








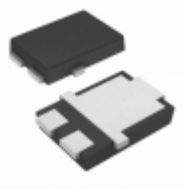


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|  | <h2>S4PJ-M3/86A</h2> |
| | <p>Hersteller-Teilenummer: S4PJ-M3/86A</p> <hr/> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <hr/> <p>Teil der Beschreibung: DIODE GEN PURP 600V 4A TO277A</p> <hr/> <p>Datenblätter:  S4PJ-M3/86A.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 2000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|------------------------------------|------------------------------------------------------------------------|
| Teilenummer | S4PJ-M3/86A |
| Hersteller | Vishay / Semiconductor - Diodes Division |
| Beschreibung | DIODE GEN PURP 600V 4A TO277A |
| Kategorie | Diskrete Halbleiterprodukte > Dioden-Gleichrichter- |
| Teilstatus | 2000 pcs Stock |
| Serie | eSMP® |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-277, 3-PowerDFN |
| Supplier Device-Gehäuse | TO-277A (SMPC) |
| Diodentyp | Standard |
| Strom - Richt (Io) | 4A |
| Spannung - Forward (Vf) (Max) @ If | 1.1V @ 4A |
| Strom - Sperrleckstrom @ Vr | 10µA @ 600V |
| Spannung - Sperr (Vr) (max) | 600V |
| Geschwindigkeit | Standard Recovery >500ns, > 200mA (Io) |
| Rückwärts-Erholzeit (Trr) | 2.5µs |
| Betriebstemperatur - Anschluss | -55°C ~ 150°C |
| Kapazität @ Vr, F | 30pF @ 4V, 1MHz |
| Verpackung | Original-Reel® |

S4PJ-M3/86A ist neu im Original, Suche S4PJ-M3/86A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S4PJ-M3/86A Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S4PJ-M3/86A: Info@Y-IC.com

Sie können auch interessiert sein:

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|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|  <p>S4PJ-M3/86A Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 4A TO277A</p> |  <p>S4PJ-M3/87A Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 4A TO277A</p> |  <p>S4PJHM3/86A Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 4A TO277A</p> |  <p>S4PJ-M3/87A Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 4A TO277A</p> |
|  <p>S4PGHM3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 4A TO277A</p> |  <p>S4PGHM3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 4A TO277A</p> |  <p>S4PGHM3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 4A TO277A</p> |  <p>S4PJHM3/86A Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 4A TO277A</p> |

heiße Teile

Mehr

| | | | | |
|---------------------|----------------|--------------------|-----------------------|-----------------|
| 06031C331JAT2A | 08053A392GAT2A | AP432N-B-AD | D C0603X5R1C103K030BA | C1005C0G1H5R6C |
| C3225X5R1E106KT000N | CD74AC161M96 | CPH6021-TL-H | CSR8610B04-IBBC-R | CY7C68310-80AC |
| FDMF6823A | FS30S06VE3 | GRM033R61A223ME84D | IP-231-EX | LH75411N0M100C0 |
| LMH6733MQX | MC79L05ACDR2 | PT8A2620W | RR268M-600 | S4PB-M3/86A |
| S4PB-M3/86A | S4PBHM3/86A | S4PBHM3/86A | S4PD-M3/86A | S4PD-M3/86A |
| S4PDHM3/86A | S4PDHM3/86A | D S4PG-M3/86A | S4PG-M3/86A | S4PGHM3/86A |
| S4PGHM3/86A | D S4PJ-M3/86A | S4PJHM3/86A | S4PJHM3/86A | S4PK-M3/86A |
| S4PK-M3/86A | S4PKHM3/86A | S4PKHM3/86A | S4PM-M3/86A | S4PM-M3/86A |
| S4PMHM3/86A | S4PMHM3/86A | SAYFH2G53CC0F0AR05 | D SN74LVC74APWR | STD27GK12 |
| TD18N14LOF | TP13064AN | TT104N12KOF | VI-J20-05 | WE2100A33P |

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